PNP/NPN Epitaxial Planar Silicon Transistors



## 2SA1520/2SC3914

# **Switching Applications (with Bias Resistance)**

### **Applications**

· Switching circuits, inverter circuits, interface circuits, driver circuits.

#### **Features**

· On-chip bias resistance : R1=2.2k $\Omega$ , R2=10k $\Omega$ .

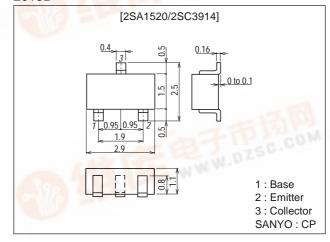
· Small-sized package : CP.

· Large current capacity : I<sub>C</sub>=500mA.

### **Package Dimensions**

unit:mm

2018B



(): 2SA1520

### **Specifications**

#### **Absolute Maximum Ratings** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CBO</sub>		(-)50	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>		(-)50	V
Emitter-to-Base Voltage	V <sub>EBO</sub>	and the later the	(-)6	V
Collector Current	IC	LES THE W	(–)500	mA
Collector Current (Pulse)	I <sub>CP</sub>	190 74 - 4	(–)800	mA
Collector Dissipation	PC	5/10	200	mW
Junction Temperature	Tj Tj	Jhrs. 4	150	°C
Storage Temperature	Tstg	COM	-55 to +150	°C

#### **Electrical Characteristics** at Ta = 25°C

Parameter	Symbol	Conditions		Ratings		
	Symbol		min	typ	max	Unit
Collector Cutoff Current	ICBO	V <sub>CB</sub> =(-)40V, I <sub>E</sub> =0			(-)0.1	μA
	ICEO	V <sub>CE</sub> =(-)40V, I <sub>B</sub> =0	1	-11	(-)0.5	μA
Emitter Cutoff Current	I <sub>EBO</sub>	V <sub>EB</sub> =(-)5V, I <sub>C</sub> =0	(-)315	(-)410	(-)590	μA
DC Current Gain	h <sub>FE</sub>	V <sub>CE</sub> =(-)5V, I <sub>C</sub> =(-)10mA	50			
Gain-Bandwidth Product	-	V <sub>CE</sub> =(-)10V, I <sub>C</sub> =(-)5mA		250		MHz
	İΤ			(200)		MHz

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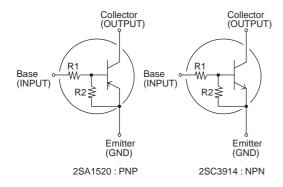
### 2SA1520/2SC3914

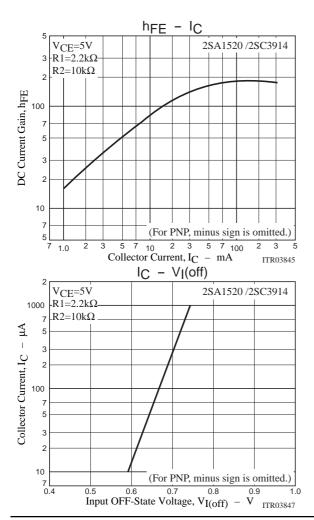
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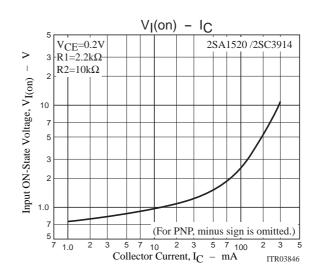
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Uill
Output Capacitance	C <sub>ob</sub>	V <sub>CB</sub> =(-)10V, f=1MHz		3.7		pF
				(5.5)		pF
Collector-to-Emitter Saturation Voltage	VCE(sat)	I <sub>C</sub> =(-)50mA, I <sub>B</sub> =(-)2.5mA		(-)0.1	(-)0.3	V
Collector-to-Base Breakdown Voltage	V <sub>(BR)</sub> CBO	I <sub>C</sub> =(-)10μA, I <sub>E</sub> =0	(-)50			V
Collector-to-Emitter Breakdown Voltage	V <sub>(BR)</sub> CEO	I <sub>C</sub> =(-)100μA, R <sub>BE</sub> =∞	(-)50			V
Input OFF-State Voltage	V <sub>I(off)</sub>	$V_{CE}=(-)5V, I_{C}=(-)100\mu A$	(-)0.5	(-)0.67	(-)0.9	V
Input ON-State Voltage	V <sub>I(on)</sub>	V <sub>CE</sub> =(-)0.2V, I <sub>C</sub> =(-)50mA	(-)0.7	(-)1.6	(-)3.0	V
Input Resistance	R1		1.5	2.2	2.9	kΩ
Resistance Ratio	R1/R2		0.198	0.22	0.242	

Marking 2SA1520: NL, 2SC3914: VY

#### **Electrical Connection**







#### 2SA1520/2SC3914

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